

BTW68

30 A SCRs

Features

On-state rms current: 30 ABlocking voltage: up to 1200 V

■ Gate current: 50 mA

■ UL 2500 V insulation (file ref E81734)

Description

Available in a high power insulated package, the BTW68 series is suitable for applications where power handling and power dissipation are critical such as solid state relays, welding equipment and high power motor control.

Based on a clip assembly technology, this device offers a superior performance in surge current handling capabilities.

Thanks to the internal ceramic pad, the device provides high voltage insulation (2500 V_{RMS}) and complies with UL standards (file ref: E81734).

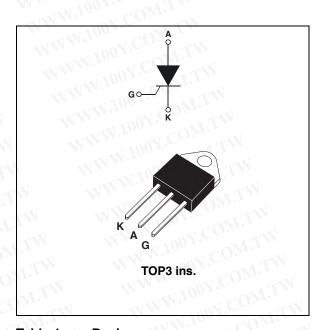


Table 1. Device summary

Symbol	Value
I _{T(RMS)}	30 A
V _{DRM} /V _{RRM}	600 to 1200 V
I _{GT}	50 mA
- ANI:	-177

BTW68

Characteristics 1

100Y.COM.TW Absolute maximum ratings (limiting values)

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Symbol	Paramete	r 100 Y		Value	Unit
I _{T(RMS)}	On-state current rms (180° conduction	n angle)	T _c = 80 °C	30	Α
IT _(AV)	Average on-state current (180° condu	ction angle)	T _c = 80 °C	19	Α
· W	Non repetitive surge peak on-state	$t_p = 8.3 \text{ ms}$	T 05 °C	420	۸
I _{TSM}	current	$t_p = 10 \text{ ms}$	$-T_j = 25 ^{\circ}C$	400	Α
l ² t	I ² t Value for fusing	WWW	T _j = 25 °C	800	A ² s
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$	F = 60 Hz	T _j = 125 °C	100	A/µs
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 125 °C	8	Α
P _{G(AV)}	Average gate power dissipation		T _j = 125 °C	CONT.TY	W
T _{stg} T _j	Storage junction temperature range Operating junction temperature range	N v	NWW.100	- 40 to + 150 - 40 to + 125	°C
V_{RGM}	Maximum peak reverse gate voltage		WWW	C 5	VV

Electrical characteristics (T_i = 25 °C, unless otherwise specified)

Symbol	Test conditions			Value	Unit
I _{GT}	$V_D = 12 \text{ V}, R_1 = 33 \Omega$	TW	MIN.	50	mA
V _{GT}	VD = 12 V, NL = 33 32		MAX.	1.5	V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$	T _j = 125 °C	MIN.	0.2	V
t _{gt}	$V_D = V_{DRM}$, $I_G = 200$ mA, $dI_G/dt = 1.5$ A/ μ	is	TYP.	2	μs
I ^H CC	I _T = 500 mA, gate open	TW	MAX.	75	mA
L C	$I_G = 1.2 \times I_{GT}$	TW	TYP.	40	mA
dV/dt	$V_{D} = 67 \% V_{DRM}$ $V_{DRM} = 800 V$	T _i = 125 °C	MIN.	500	V/µs
uv/ut	gate open $V_{DRM} = 1000 V_{DRM}$	$I_{j} = 125 \text{ C}$	IVIIIN.	250	V/μ
V _{TM}	$I_{TM} = 60 \text{ A}, t_p = 380 \mu\text{s}$	N.COM.	MAX.	2.1	V
I _{DRM}	A COMPANY MANAGEMENTS	T _j = 25 °C	MAX.	20	μA
I _{RRM}	$V_{DRM} = V_{RRM}$	T _j = 125 °C	IVIAA.	6	mA
tq	$V_D = 67\% \ V_{DRM}, \ I_{TM} = 60 \ A, \ V_R = 75 \ V$ $dI_{TM}/dt = 30 \ A/\mu s, \ dV_D/dt = 20 \ V/\mu s$	T _j = 125 °C	TYP.	100	μs

Table 4. Thermal resistance

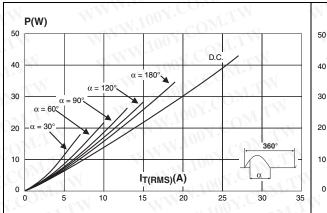
Symbol	Paramet	er	Value	Unit
R _{th(j-c)}	Junction to case (D.C.)	MAN TOO TO	1.1	°C/W
R _{th(j-a)}	Junction to ambient	11 1007	50	°C/W

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Characteristics

Figure 1. Maximum average power dissipation versus average on-state current

Figure 2. Correlation between maximum average power dissipation and maximum allowable temperature



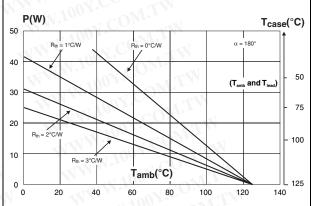
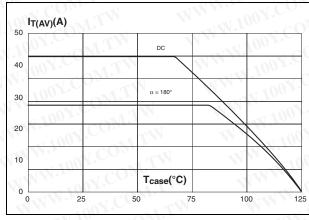


Figure 3. Average on-state current versus case Figure 4. temperature

Relative variation of thermal impedance versus pulse duration



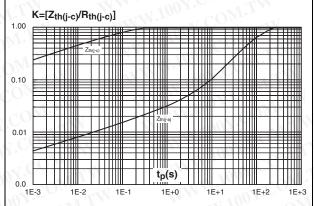
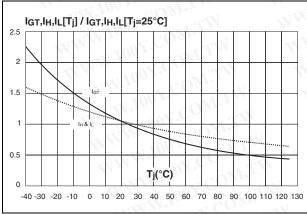
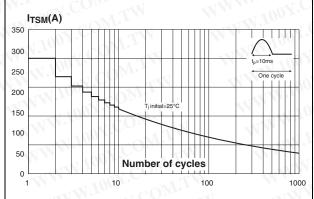


Figure 5. Relative variation of gate trigger current versus junction temperature

Figure 6. Surge peak on-state current versus number of cycles

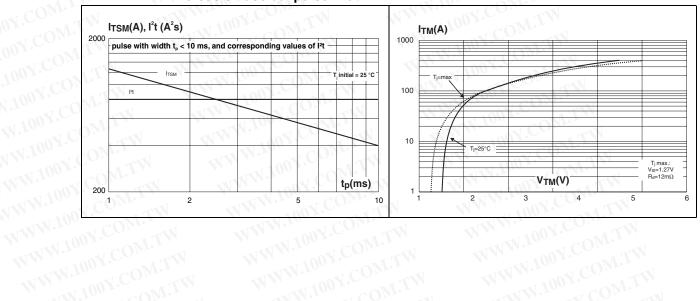




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Figure 7. Non repetitive surge peak on-state Figure 8. On-state characteristics current and corresponding value of (maximum values) I²t versus sinusoidal pulse width



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Ordering information scheme 2

Figure 9. Ordering information scheme

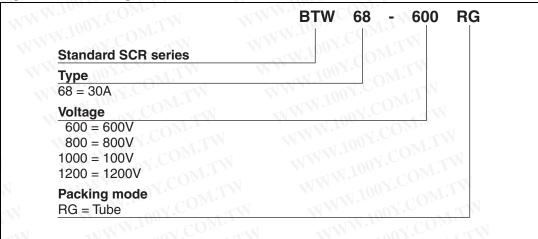


Table 5. **Product Selector**

Part numbers	Voltage (xxx)				Sensitivity	Package
	600 V	800 V	1000 V	1200 V	NY . 100 Y.C	T.MO
BTW68-600RG	X	100 X.C.	MIM	1	- 50 mA	TOP3 Ins.
BTW68-800RG	MMA	X	OM.TV			
BTW68-1000RG	MM	100Y.	X			
BTW68-1200RG	VVV	W	Co	X	WWW	

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Package information 3

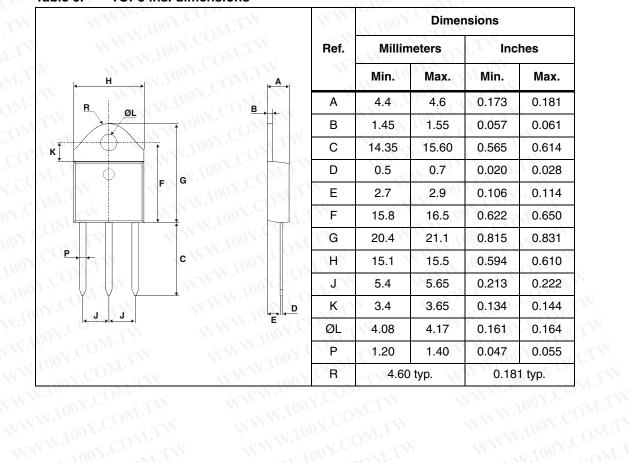
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- Http://www.100y.com.tw Epoxy meets UL94,V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

Table 6. TOP3 ins. dimensions



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Ordering information 4

Table 7. **Ordering information**

Ordering info	ormation				
Table 7. Orderin	g information Marking	Package	Weight	Base qty	Delivery mode
BTW68-600RG	BTW68-600	WWW.100	Y.CON	TW	, ,
BTW68-800RG	BTW68-800	WWW.I	ON.CO	WILL	- .
BTW68-1000RG	BTW68-1000	TOP3 ins.	4.5 g	30	Tube
BTW68-1200RG	BTW68-1200	WWW	LOON.C	OM.	
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Table 8. Document revision history

Mar-1995	WIN	Initial release.
13-Feb-2006	2	TOP3 Insulated delivery mode changed from bulk to tube. ECOPACK statement added.
29-Jul-2010	3	Deleted part number BTW68-200RG. Updated <i>Table 2</i> , <i>Figure 7</i> an alpha angle in <i>Figure 1</i> .

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